



TS4973

1.2W TWO AUDIO INPUTS WITH GAIN CONTROL POWER AMPLIFIER WITH STANDBY MODE ACTIVE LOW

ADVANCE DATA

- OPERATING FROM $V_{CC} = 2.8V$ to $5.5V$
- RAIL TO RAIL OUTPUT
- 1.2W OUTPUT POWER @ $V_{CC}=5V$, THD=1%, F=1kHz, with 8Ω Load
- ULTRA LOW CONSUMPTION IN STANDBY MODE (10nA)
- 53dB PSRR @ 217Hz from 2.8 to 5V
- LOW POP & CLICK
- ULTRA LOW DISTORTION (0.05%)
- GAIN SETTINGS PIN : GS
- UNITY GAIN STABLE
- FLIP CHIP PACKAGE 9 x 300 μ m bumps

DESCRIPTION

At 3.3v, the TS4973 is an Audio Power Amplifier capable of delivering 400mW of continuous RMS output power into a 8Ω bridged-tied loads with 1% THD+N, and 30mW(typ) per channel of continuous average power into stereo 32Ω BTL loads with 0.5% THD+N from 20Hz to 20kHz. An external standby mode control reduces the supply current to less than 10nA. An internal over-temperature shutdown protection is provided.

The TS4973 has been designed for high quality audio applications such as mobile phones and to minimize the number of external components. It has two inputs which can be used to switch the gain between 6dB (internal) or a user's adjustable gain setting with one external resistance.

APPLICATIONS

- Mobile Phones (Cellular / Cordless)
- PDAs
- Laptop/Notebook computers
- Portable Audio Devices

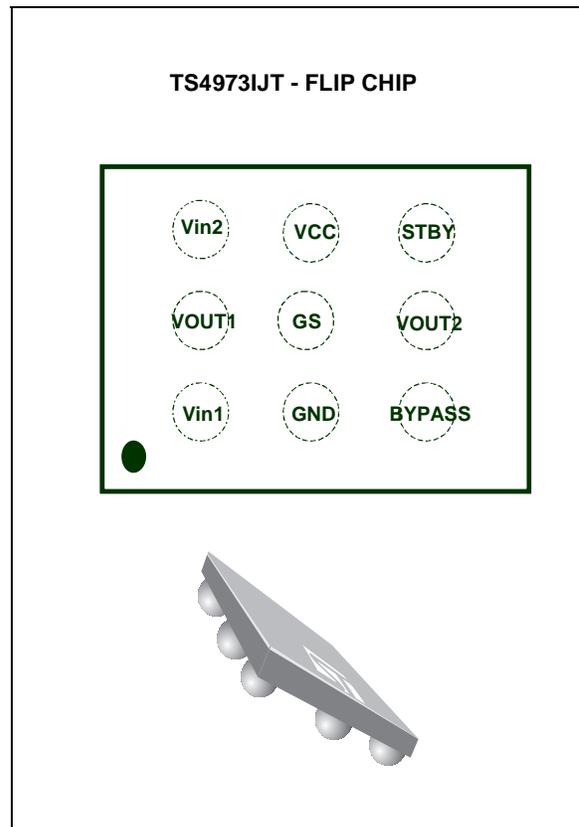
ORDER CODE

Part Number	Temperature Range	Package	Marking
		J	
TS4973IJT	-40, +85°C	•	A73

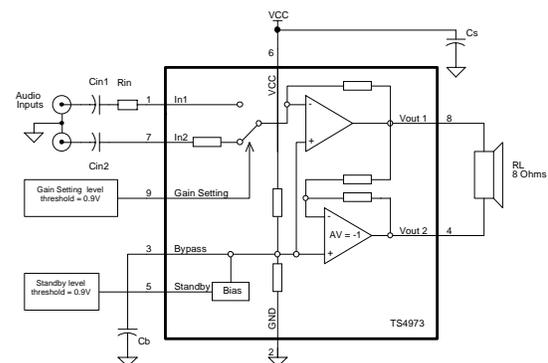
J = Flip Chip Package - only available in Tape & Reel (JT)

February 2003

PIN CONNECTIONS (top view)



TYPICAL APPLICATION SCHEMATIC



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage ¹⁾	6	V
V_i	Input Voltage ²⁾	G_{ND} to V_{CC}	V
T_{oper}	Operating Free Air Temperature Range	-40 to + 85	°C
T_{stg}	Storage Temperature	-65 to +150	°C
T_j	Maximum Junction Temperature	150	°C
R_{thja}	Thermal Resistance Junction to Ambient ³⁾	200	°C/W
P_d	Power Dissipation	Internally Limited ⁴⁾	
ESD	Human Body Model	2	kV
ESD	Machine Model	200	V
Latch-up	Latch-up Immunity	200	mA
	Lead Temperature (soldering, 10sec)	250	°C

1. All voltages values are measured with respect to the ground pin.

2. The magnitude of input signal must never exceed $V_{CC} + 0.3V / G_{ND} - 0.3V$

3. Device is protected in case of over temperature by a thermal shutdown active @ 150°C.

4. Exceeding the power derating curves during a long period, involves abnormal operating condition.

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	2.8 to 5.5	V
V_{ICM}	Common Mode Input Voltage Range	G_{ND} to $V_{CC} - 1.5V$	V
V_{STB}	Standby Voltage Input : Device ON Device OFF	$1.5 \leq V_{STB} \leq V_{CC}$ $G_{ND} \leq V_{STB} \leq 0.4$	V
V_{GS}	Gain Setting Voltage Input : External Gain (In1 Input) Internal Gain (In2 Input)	$1.5 \leq V_{STB} \leq V_{CC}$ $G_{ND} \leq V_{STB} \leq 0.4$	V
R_L	Load Resistor	4 - 32	Ω
R_{thja}	Thermal Resistance Junction to Ambient ¹⁾	90	°C/W

1. With Heat Sink Surface = 125mm²

ELECTRICAL CHARACTERISTICS

$V_{CC} = +5V$, $GND = 0V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
I_{CC}	Supply Current No input signal, no load		6	8	mA
$I_{STANDBY}$	Standby Current ¹⁾ No input signal, $V_{stdby} = Gnd$, $R_L = 8\Omega$		10	1000	nA
V_{oo}	Output Offset Voltage No input signal, $R_L = 8\Omega$		5	20	mV
P_o	Output Power THD = 1% Max, $f = 1kHz$, $R_L = 8\Omega$	0.85	1.2		W
BTL GAIN	GS = Low input signal $V_{in} = 100mV$ rms, $R_L = 8\Omega$	5.6	6	6.4	dB
THD + N	Total Harmonic Distortion + Noise $P_o = 250mW$ rms, GS = Low, $20Hz < f < 20kHz$, $R_L = 8\Omega$		0.1		%
PSRR	Power Supply Rejection Ratio ²⁾ $F = 217Hz$, $R_L = 8\Omega$, GS = Low, Vripple = 200mV rms Input Grounded, $C_{in} = 220nF$, $C_b = 1\mu F$	50	53		dB
PSRR	Power Supply Rejection Ratio ³⁾ $F = 217Hz$, $R_L = 8\Omega$, GS = Low, Vripple = 200mV rms Input floating, $C_b = 1\mu F$		75		dB
Z_{in}	Input Impedance GS = Low	37.5	50	62.5	K Ω
R_{feed}	Internal Feedback Resistor	37.5	50	62.5	K Ω
Φ_M	Phase Margin at GS = Low $R_L = 8\Omega$, $C_L = 500pF$		70		Degrees
GM	Gain Margin $R_L = 8\Omega$, $C_L = 500pF$		20		dB
GBP	Gain Bandwidth Product $R_L = 8\Omega$		2		MHz

1. Standby mode is activated when V_{stdby} is tied to Gnd

2. Dynamic measurements - $20 \cdot \log(\text{rms}(V_{out})/\text{rms}(V_{ripple}))$. Vripple is an added sinus signal to V_{cc} @ $f = 217Hz$

3. Dynamic measurements - $20 \cdot \log(\text{rms}(V_{out})/\text{rms}(V_{ripple}))$. Vripple is an added sinus signal to V_{cc} @ $f = 217Hz$

ELECTRICAL CHARACTERISTICS

$V_{CC} = +3.3V$, $GND = 0V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)⁴⁾

Symbol	Parameter	Min.	Typ.	Max.	Unit
I_{CC}	Supply Current No input signal, no load		5.5	8	mA
$I_{STANDBY}$	Standby Current ¹⁾ No input signal, $V_{stdby} = V_{CC}$, $R_L = 8\Omega$		10	1000	nA
V_{OO}	Output Offset Voltage No input signal, $R_L = 8\Omega$		5	20	mV
P_o	Output Power THD = 1% Max, $f = 1kHz$, $R_L = 8\Omega$	350	500		mW
BTL GAIN	GS = Low input signal $V_{in} = 100mV$ rms, $R_L = 8\Omega$	5.6	6	6.4	dB
THD + N	Total Harmonic Distortion + Noise $P_o = 250mW$ rms, $G_v = 2$, $20Hz < f < 20kHz$, $R_L = 8\Omega$		0.1		%
PSRR	Power Supply Rejection Ratio ²⁾ $f = 217Hz$, $R_L = 8\Omega$, GS = Low, Vripple = 200mV rms Input Grounded, $C_{in} = 220nF$, $C_b = 1\mu F$	50	53		dB
PSRR	Power Supply Rejection Ratio ³⁾ $f = 217Hz$, $R_L = 8\Omega$, GS = Low, Vripple = 200mV rms Input floating, $C_b = 1\mu F$		75		dB
Z_{in}	Input Impedance GS = Low	37.5	50	62.5	K Ω
R_{feed}	Internal Feedback Resistor	37.5	50	62.5	K Ω
Φ_M	Phase Margin at Unity Gain $R_L = 8\Omega$, $C_L = 500pF$		70		Degrees
GM	Gain Margin $R_L = 8\Omega$, $C_L = 500pF$		20		dB
GBP	Gain Bandwidth Product $R_L = 8\Omega$		2		MHz

1. Standby mode is activated when V_{stdby} is tied to V_{CC}

2. Dynamic measurements - $20 \cdot \log(\text{rms}(V_{out})/\text{rms}(V_{ripple}))$. Vripple is an added sinus signal to V_{CC} @ $f = 217Hz$

3. Dynamic measurements - $20 \cdot \log(\text{rms}(V_{out})/\text{rms}(V_{ripple}))$. Vripple is an added sinus signal to V_{CC} @ $f = 217Hz$

4. All electrical values are made by correlation between 2.8V and 5V measurements

ELECTRICAL CHARACTERISTICS $V_{CC} = 2.8V$, $GND = 0V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
I_{CC}	Supply Current No input signal, no load		5.5	8	mA
$I_{STANDBY}$	Standby Current ¹⁾ No input signal, $V_{stdby} = V_{CC}$, $R_L = 8\Omega$		10	1000	nA
V_{OO}	Output Offset Voltage No input signal, $R_L = 8\Omega$		5	20	mV
BTL GAIN	GS = Low input signal $V_{in} = 100mV$ rms, $R_L = 8\Omega$	5.6	6	6.4	dB
P_o	Output Power THD = 1% Max, $f = 1kHz$, $R_L = 8\Omega$	250	350		mW
THD + N	Total Harmonic Distortion + Noise $P_o = 200mW$ rms, $G_v = 2$, $20Hz < f < 20kHz$, $R_L = 8\Omega$		0.1		%
PSRR	Power Supply Rejection Ratio ²⁾ $F = 217Hz$, $R_L = 8\Omega$, GS = Low, $V_{ripple} = 200mV$ rms Input Grounded, $C_{in} = 220nF$, $C_b = 1\mu F$	50	53		dB
PSRR	Power Supply Rejection Ratio ³⁾ $F = 217Hz$, $R_L = 8\Omega$, GS = Low, $V_{ripple} = 200mV$ rms Input Floating, $C_b = 1\mu F$		75		dB
Z_{in}	Input Impedance GS = Low	37.5	50	62.5	K Ω
R_{feed}	Internal Feedback Resistor	37.5	50	62.5	K Ω
Φ_M	Phase Margin at Unity Gain $R_L = 8\Omega$, $C_L = 500pF$		70		Degrees
GM	Gain Margin $R_L = 8\Omega$, $C_L = 500pF$		20		dB
GBP	Gain Bandwidth Product $R_L = 8\Omega$		2		MHz

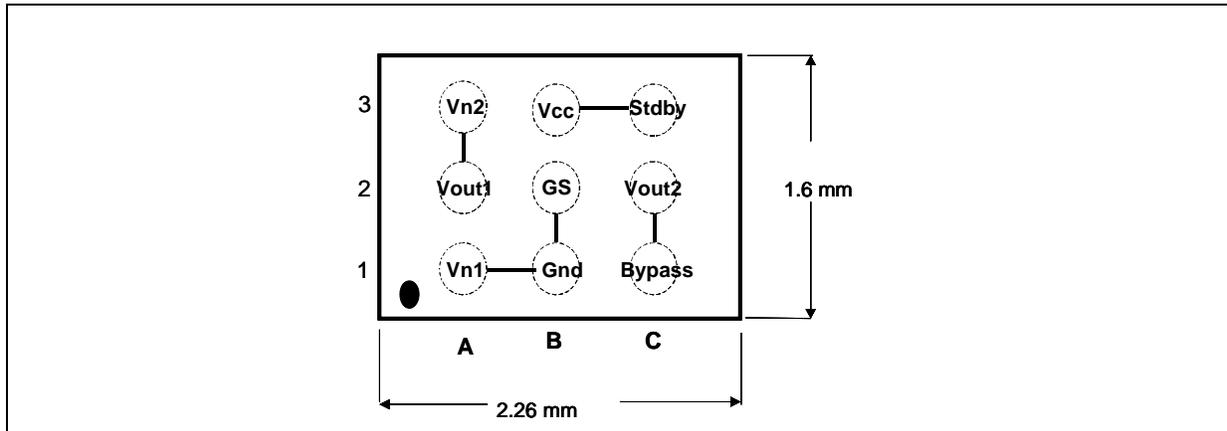
1. Standby mode is activated when V_{stdby} is tied to Gnd2. Dynamic measurements - $20 \cdot \log(\text{rms}(V_{out})/\text{rms}(V_{ripple}))$. V_{ripple} is an added sinus signal to V_{CC} @ $F = 217Hz$ 3. Dynamic measurements - $20 \cdot \log(\text{rms}(V_{out})/\text{rms}(V_{ripple}))$. V_{ripple} is an added sinus signal to V_{CC} @ $F = 217Hz$

Components	Functional Description
Rin	Inverting input resistor which sets the closed loop gain (when GS = high) in conjunction with the internal feedback resistor Rfeed. This resistor also forms a high pass filter with Cin1 $F_c = 1 / (2 \times \text{Pi} \times \text{Rin} \times \text{Cin1})$
Cin1	Input coupling capacitor which blocks the DC voltage at the amplifier input terminal In1
Cin2	Input coupling capacitor which blocks the DC voltage at the amplifier input terminal In2. This capacitor also forms a high pass filter with Zin (internal input impedance when Gs = Low $F_c = 1 / (2 \times \text{Pi} \times \text{Zin} \times \text{Cin2})$
Cs	Supply Bypass capacitor which provides power supply filtering (Recommended value = 1µF)
Cb	Bypass pin capacitor which provides half supply filtering (Recommended value = 1µF)
Gv	Closed loop gain in BTL configuration When Gs = Low, Gv = 2 or 6dB When GS = high, Gv = 2 x (Rfeed / Rin). Rfeed value see Electrical Characteristics.

REMARKS

1. All measurements, except PSRR measurements, are made with a supply bypass capacitor Cs = 1µF.
2. The standby response time is about 1µs.

DAISY CHAIN MECHANICAL DATA (Top View : all drawings dimensions are in millimeters)



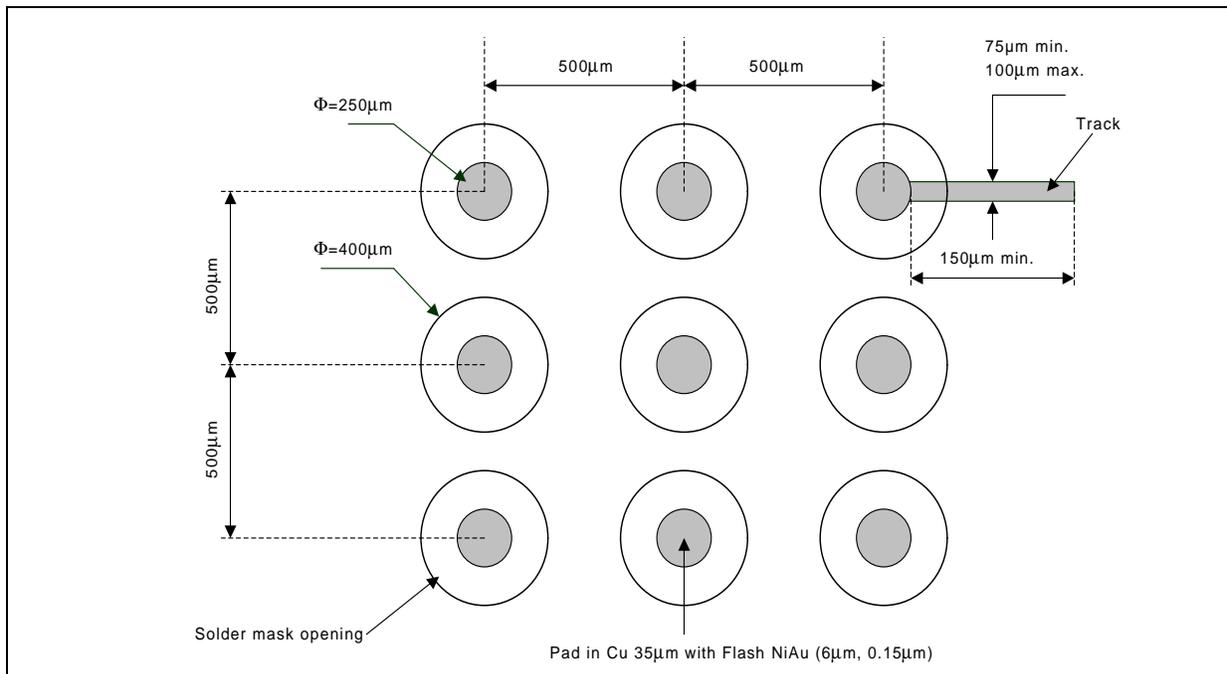
REMARKS

Daisy chain sample is featuring pins connection two by two. The schematic above is illustrating the way connecting pins each other. This sample is used for testing continuity on board. PCB needs to be designed on the opposite way, where pin connections are not done on daisy chain samples. By that way, just connecting an Ohm meter between pin 8 and pin 1, the soldering process continuity can be tested.

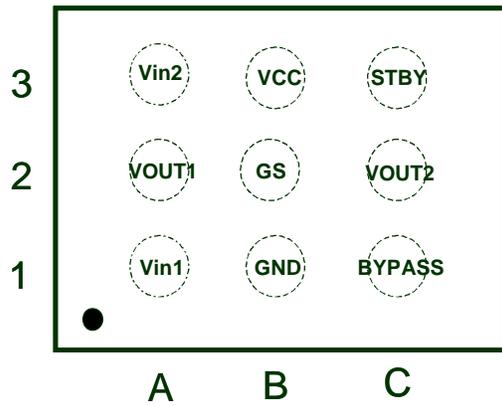
ORDER CODE

Part Number	Temperature Range	Package	Marking
		J	
TSDC05IJT	-40, +85°C	•	DC5

TS4973 Footprint Recommendation



PIN OUT (top view)

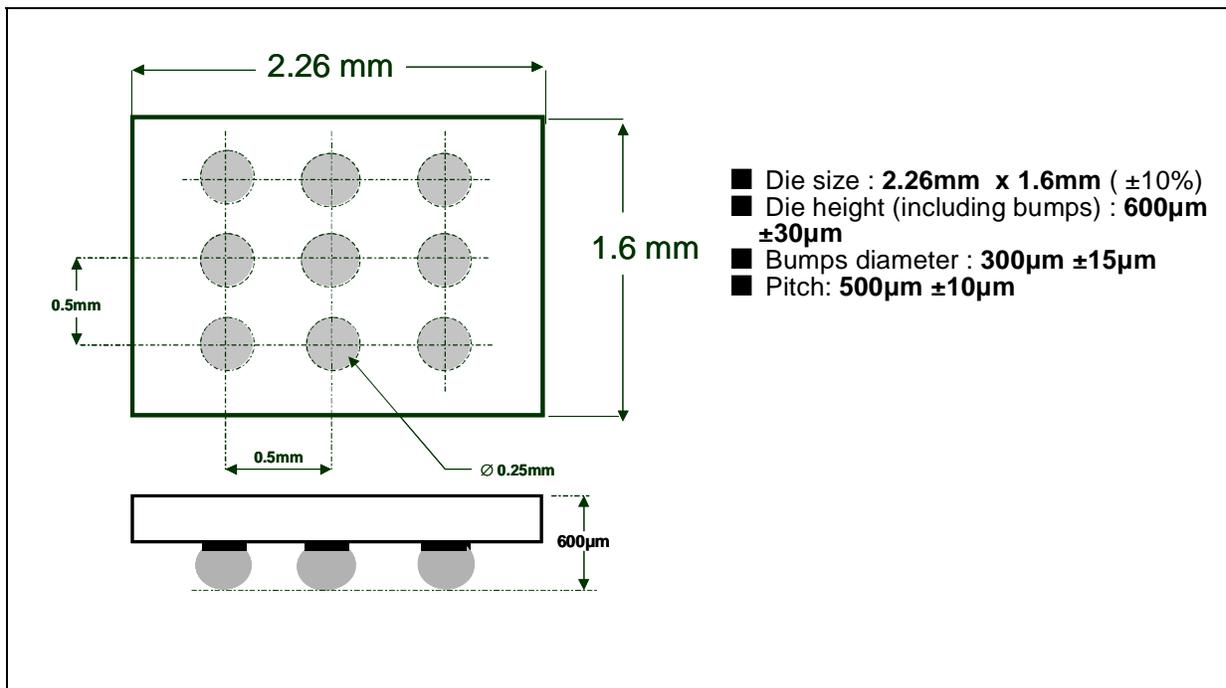


MARKING (top view)

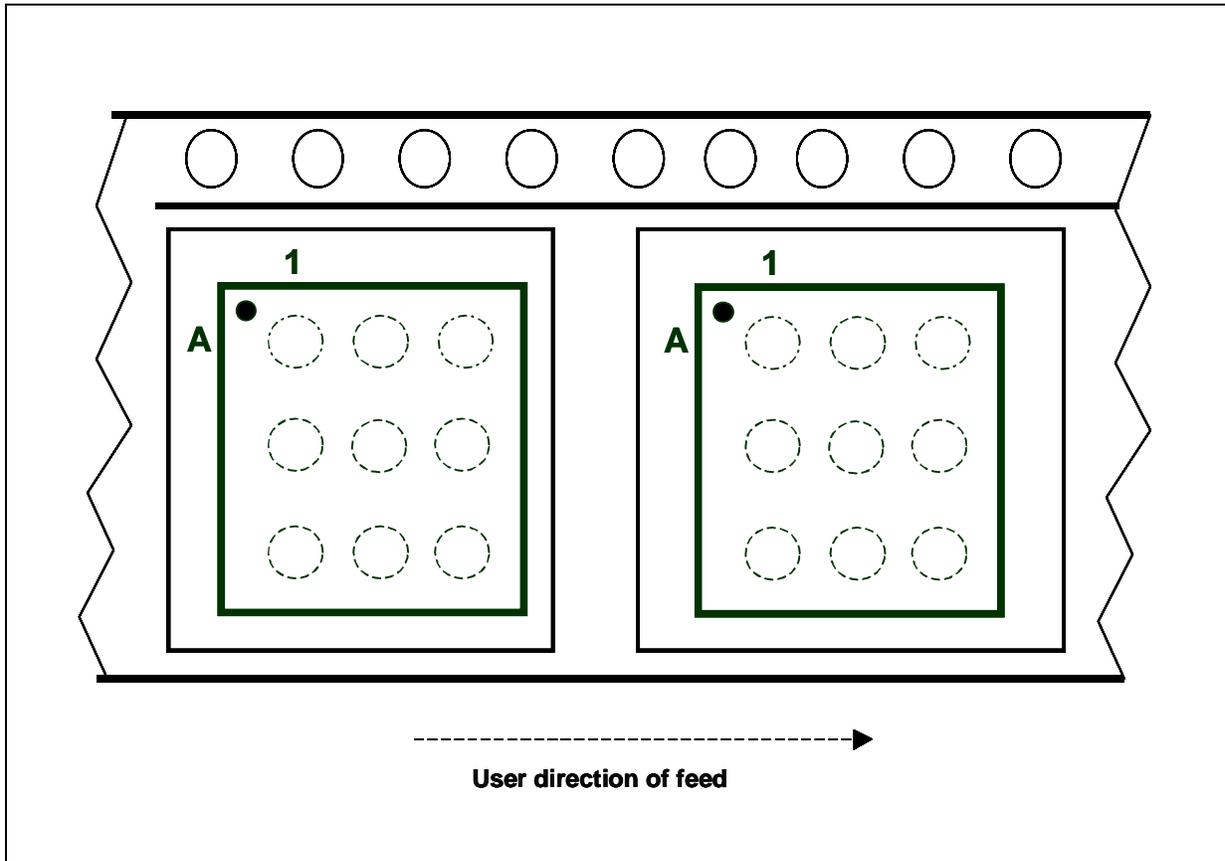


- Logo : ST
- Part Number : A73
- Date Code : YWW
- The Dot is for marking pin A1

PACKAGE MECHANICAL DATA
FLIP CHIP - 9 BUMPS



TAPE & REEL SPECIFICATION (top view)



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